Unit: mm

±0.2

0.45±0.05

Base : Collector 3 : Emitter M-A1 Package

(1.0) <u>(</u>

2.5±0.1

**3.5**±0.1

6.9+0.\*

(0.85)

R 0

0101

**B** 0 9

# 2SD1051

## Silicon NPN epitaxial planar type

For low-frequency power amplification Complementary to 2SB0819 (2SB819)

#### Features

4

- High collector-emitter voltage (Base open)  $V_{CEO}$
- Low collector power dissipation P<sub>C</sub>
- M type package allowing easy automatic and manual insertion as well as stand-alone fixing to the printed circuit board.

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit		
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	50	V		
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	40	V		
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	5	V		
Collector current	I <sub>C</sub>	1.5	A		
Peak collector current	I <sub>CP</sub>	3	А		
Collector power dissipation *	Pc	1	W		
Junction temperature	Tj	150	°C		
Storage temperature	T <sub>stg</sub>	-55 to +150	°C		

### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Peak collector current	I <sub>CP</sub>	3 A .	•	$\overline{\mathcal{O}}$			
Collector power dissipation *	P <sub>C</sub>	1 W	Š				
Junction temperature T <sub>j</sub> 150 °C							
Storage temperature $T_{stg}$ -55 to +150 °C							
Note) *: Printed circuit board: Copper foil area of 1 cm <sup>2</sup> or more, and the							
board thickness of 1.7 mm for the collector portion							
Peak collector current $I_{CP}$ 3ACollector power dissipation * $P_C$ 1WJunction temperature $T_j$ 150°CStorage temperature $T_{stg}$ -55 to +150°CNote) *: Printed circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portionThe collector portionElectrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$ C							
Parameter	Symbol	Conditions S	Min	Тур	Max	Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	$I_{\rm C} = 1 \text{ mA}, I_{\rm E} = 0$	50			V	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = 2$ mA, $I_{\rm B} = 0$	40			V	
Collector-base cutoff current (Emitter open)	I <sub>CBO</sub>	$V_{CB} = 20 V, I_B = 0$			1	μΑ	
Collector-emitter cutoff current (Base open)	I <sub>CEO</sub>	$V_{CE} = 10$ V, $I_B = 0$			100	μΑ	
Emitter-base cutoff current (Collector open)	I <sub>EBO</sub>	$V_{\rm EB} = 5  {\rm V},  {\rm I_C} = 0$			10	μΑ	
Forward current transfer ratio *1, 2	Ret	$V_{CE} = 5 V, I_C = 1 A$	80	120	220	_	
Collector-emitter saturation voltage *1	N <sub>CE(sat)</sub>	$I_{\rm C} = 1.5$ A, $I_{\rm B} = 0.15$ A			1	V	
Base-emitter saturation voltage *	V <sub>BE(sat)</sub>	$I_{\rm C} = 2 \text{ A}, I_{\rm B} = 0.2 \text{ A}$			1.5	V	
Transition frequency *1	f <sub>T</sub>	$V_{CB} = 5 V, I_E = -0.5 A, f = 200 MHz$		150		MHz	
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 20 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		45		pF	
(Common base, input open circuited)							

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

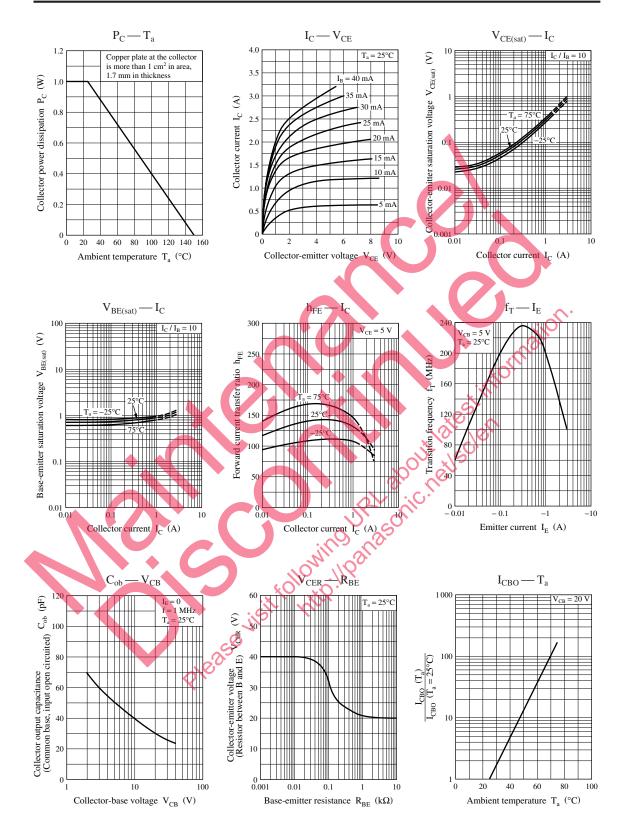
2. \*1: Pulse measurement

\*2: Rank classification

Rank	Q	R
h <sub>FE</sub>	80 to 160	120 to 220

Note) The part number in the parenthesis shows conventional part number.

## **Panasonic**



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